

Features

- 300Watts peak pulse power ($t_p = 8/20\mu s$)
- Tiny DFN1006 package
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Protection one data/power line to:
- IEC 61000-4-2 $\pm 30kV$ contact $\pm 30kV$ air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 18A (8/20 μs)



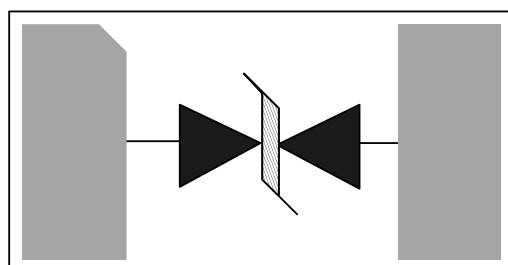
Applications

- Cell Phone Handsets and Accessories
- Microprocessor based equipment
- Personal Digital Assistants (PDA's)
- Notebooks, Desktops, and Servers
- Portable Instrumentation

Mechanical Data

- DFN1006 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

Schematic & PIN Configuration



DFN1006



Absolute Maximum Rating

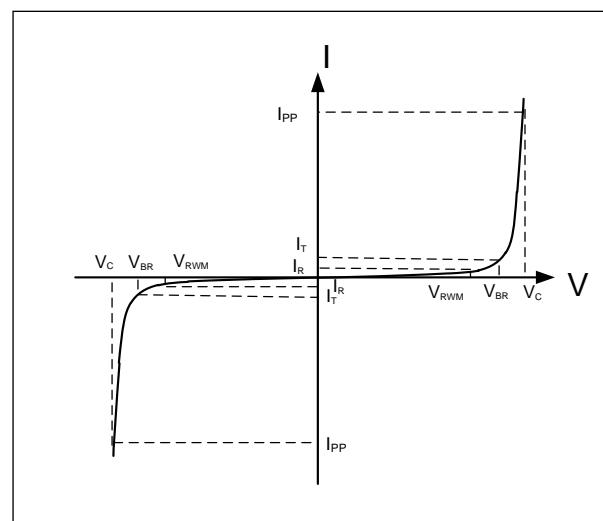
| Rating | Symbol | Value | Units |
|--|------------------|----------------|-------|
| Peak Pulse Power ($t_p = 8/20\mu s$) | P _{PP} | 300 | Watts |
| Peak Pulse Current ($t_p = 8/20\mu s$) (note1) | I _{PP} | 18 | A |
| ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact) | V _{ESD} | 30 30 | kV |
| Lead Soldering Temperature | T _L | 260(10seconds) | °C |
| Junction Temperature | T _J | -55 to + 125 | °C |
| Storage Temperature | T _{stg} | -55 to + 125 | °C |

Electrical Characteristics

| Parameter | Symbol | Conditions | Min | Typical | Max | Units |
|---------------------------|------------------|---|-----|---------|-----|-------|
| Reverse Stand-Off Voltage | V _{RWM} | | | | 8.0 | V |
| Reverse Breakdown Voltage | V _{BR} | I _T =1mA | 9.0 | | | V |
| Reverse Leakage Current | I _R | V _{RWM} =8.0V,T=25°C | | 0.1 | 0.5 | µA |
| Peak Pulse Current | I _{PP} | t _p =8/20µs | | 18 | | A |
| Clamping Voltage | V _C | I _{PP} =18A,t _p =8/20µs | | 17 | | V |
| Junction Capacitance | C _j | V _R = 0V, f = 1MHz | | 17 | | pF |

Electrical Parameters (TA = 25°C unless otherwise noted)

| Symbol | Parameter |
|------------------|--|
| I _{PP} | Maximum Reverse Peak Pulse Current |
| V _C | Clamping Voltage @ I _{PP} |
| V _{RWM} | Working Peak Reverse Voltage |
| I _R | Maximum Reverse Leakage Current @ V _{RWM} |
| V _{BR} | Breakdown Voltage @ I _T |
| I _T | Test Current |
| | |
| | |



Note.: 8/20µs pulse waveform.



Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

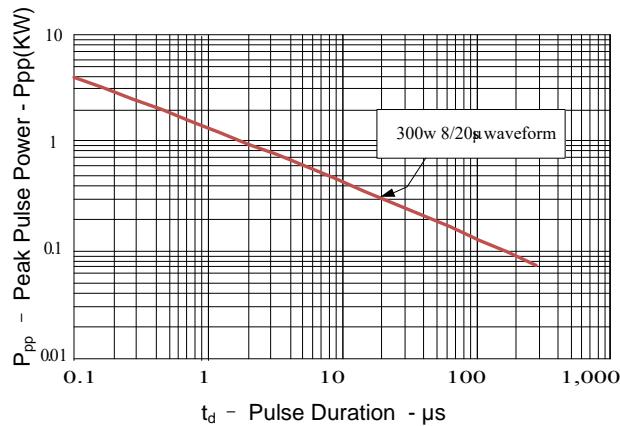


Figure 2: Power Derating Curve

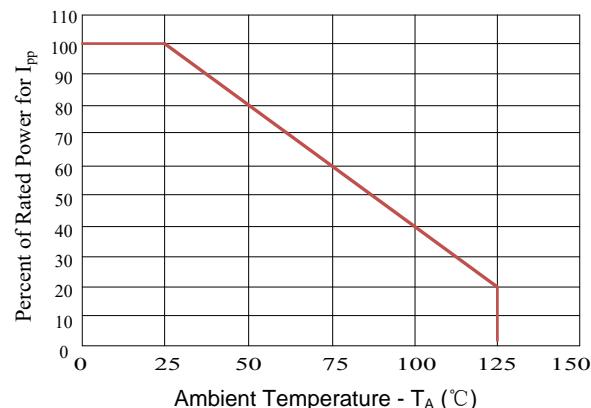


Figure 3: Pulse Waveform

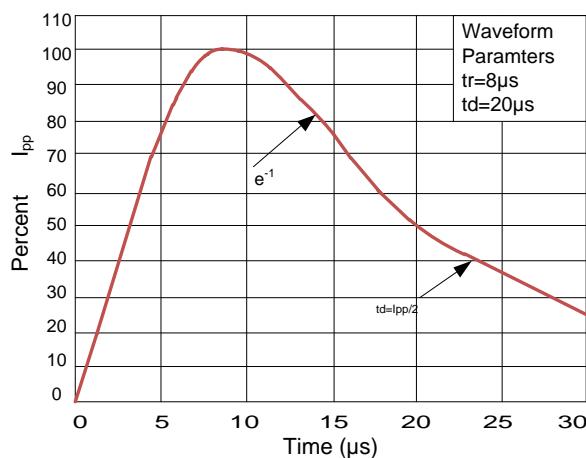
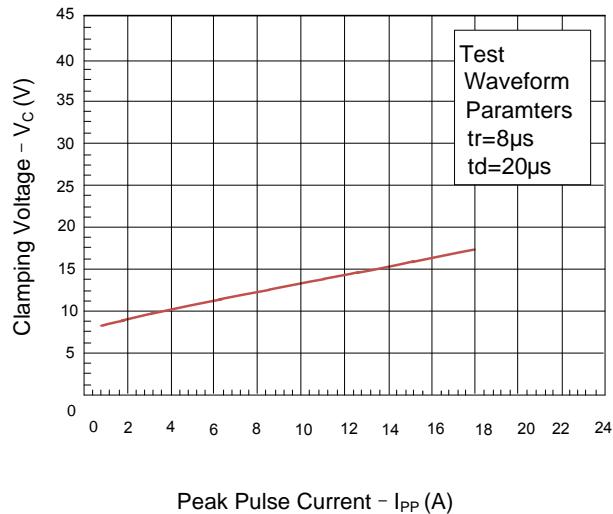
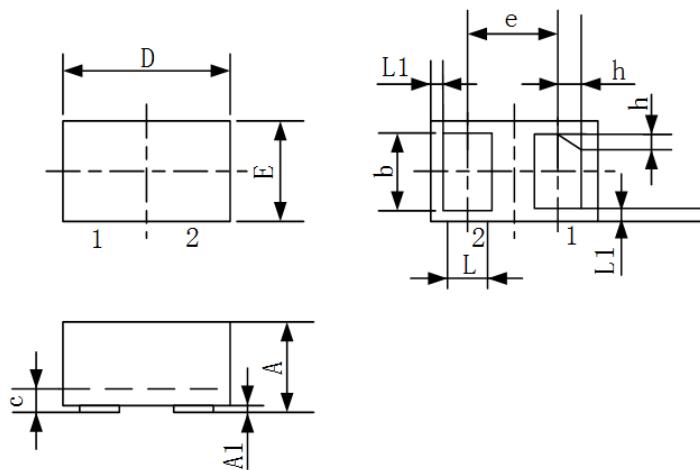


Figure 4: Clamping Voltage vs. Ipp

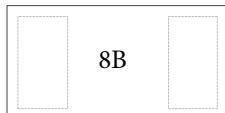


Outline Drawing – DFN1006



| SYMBOL | MILLIMETER | | |
|---------------|------------|------|------|
| | MIN | NOM | MAX |
| A | 0.40 | 0.50 | 0.55 |
| A1 | 0 | 0.02 | 0.05 |
| b | 0.45 | 0.50 | 0.55 |
| c | 0.12 | 0.15 | 0.18 |
| D | 0.95 | 1.00 | 1.05 |
| e | 0.65BSC | | |
| E | 0.55 | 0.60 | 0.65 |
| L | 0.20 | 0.25 | 0.30 |
| L1 | 0.05REF | | |
| h | 0.07 | 0.12 | 0.17 |
| 载体尺寸 (MIL) | 20*20 | | |

Marking



Ordering information

| Order code | Package | Base qty | Delivery mode |
|-------------|---------|----------|---------------|
| RLSD92Q081C | DFN1006 | 10k | Tape and reel |

